

SS52---SS520

**VOLTAGE RANGE: 20--- 200V CURRENT: 5.0 A** 

# SCHOTTKY BARRIER RECTIFIER

### **FEATURES**

- Plastic package has Underwriters Laboratory
   Flammability Classification 94V-O Utilizing
- •Metal silicon junction ,majority carrier conduction
- •Built-in strain relief
- •For surface mounted applications
- •Low power loss ,high efficiency,High surge capability
- •High current capability ,Low forward voltage drop
- •For use in low voltage ,high frequency inverters, free wheeling , and polarity protection applications
- $\bullet$  High temperature soldering guaranteed:260  $^{\circ}\text{C}/10$  seconds at terminals
- Component in accordance to RoHS 2002/95/Ec and WEEE 2002/96/EC

### **MECHANICAL DATA**

- •Case: SMB molded plastic body
- •Terminals:Lead solderable per MIL-STD-750,method 2026
- •Polarity:Color band denotes cathode end

# 0.086 (2.20) 0.077 (1.95) 0.180(4.57) 0.160(4.06) 0.096(2.44) 0.086(2.18) 0.096(2.42) 0.030(0.76) 0.008(0.203)MAX. 0.020(5.59) 0.205(5.21) Dimensions in inches and (millimeters)

### **MAXIMUM RATINGS AND CHARACTERISTICS**

@ 25°C Ambient Temperature (unless otherwise noted)Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

TYPE NUMBER		SYMBOL	SS52	SS53	SS54	SS55	SS56	SS58	SS510	SS520	UNITS
Maximum recurrent peak reverse voltage		$V_{RRM}$	20	30	40	50	60	80	100	200	V
Maximum RMS voltage		V <sub>RMS</sub>	14	21	28	35	42	57	71	140	٧
Maximum DC blocking voltage		V <sub>DC</sub>	20	30	40	50	60	80	150	200	V
Maximum Average Forward rectified		I <sub>F(AV)</sub>	5.0								А
Current0.375"(9.5mm) lead length											
Peak forw ard surge current 8.3ms single half sine-w ave		I <sub>FSM</sub>	150.0								А
superimposed on rated load											
Maximum instantaneous forward voltage at 5.0 A(Note1)		$V_{F}$	0.55		0.	.70	0.85		0.95	V	
Maximum reverse current	@T <sub>A</sub> =25℃		0.2								m A
at rated DC blocking voltage perdiode	@T <sub>A</sub> =100℃	I <sub>R</sub>		;	50.0	10.0					IIIA
Typical Thermal Resistance (Note 2)		R <sub>BJA</sub>	55.0								°C/W
Typical junction capacitance(Note 3)		Cı	500		400						
Storage Temperature		$T_{\text{STG}}$	- 55 + 150								°C
Operation Junction Temperature		T <sub>j</sub>	- 55 + 125								$^{\circ}\mathbb{C}$

NOTE: 1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas

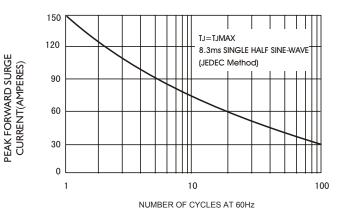


# RATINGS AND CHARACTERISTIC CURVES

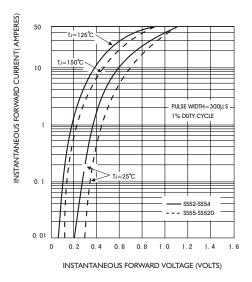
### FIG.1-FORWARD CURRENT DERATING CURVE

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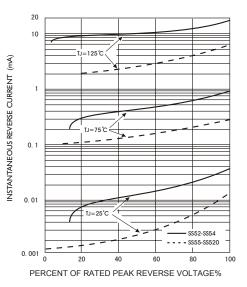
# FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



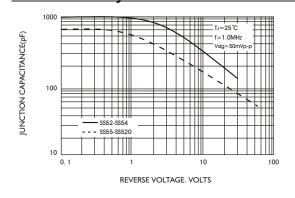
# FIG.3-TYPICAL INSTANTANE OUS FORWARD CHARACTERISTICS



# FIG.4-TYPICAL REVERSE CHARACTERISTICS



## FIG.5-TYPICAL JUNCTION CAPACITANCE



# FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

